## 500mW, High Speed Switching Diode

## FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21


## APPLICATIONS

- Switching mode power supply (SMPS)

| KEY PARAMETERS |  |  |
| :---: | :---: | :---: |
| PARAMETER | VALUE | UNIT |
| $\mathrm{I}_{\mathrm{F}}$ | 150 | mA |
| $\mathrm{~V}_{\text {RRM }}$ | 100 | V |
| $\mathrm{I}_{\mathrm{FSM}}$ | 2 | A |
| $\mathrm{~V}_{\mathrm{F}}$ at $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ | 1 | V |
| $\mathrm{~T}_{\mathrm{JMAX}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Package | DO-35 |  |
| Configuration | Singal die |  |

## MECHANICAL DATA

- Case: DO-35
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Polarity: Indicated by cathode band
- Weight: $125 \pm 4 \mathrm{mg}$


| ABSOLUTE MAXIMUM RATINGS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted $)$ |  |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | 1N4148 | 1N4448 | 1N914B | UNIT |
| Power dissipation | $\mathrm{P}_{\mathrm{D}}$ | 500 | mW |  |  |
| Repetitive peak reverse voltage | $\mathrm{V}_{\text {RRM }}$ | 100 | V |  |  |
| Non-Repetitive peak forward surge current <br> Pluse width $=1 \mu \mathrm{~s}$, Square wave | $\mathrm{I}_{\text {FSM }}$ | 2 | A |  |  |
| Non-Repetitive peak forward current | $\mathrm{I}_{\text {FM }}$ |  |  |  |  |
| Forward current | $\mathrm{I}_{\mathrm{F}}$ | 450 | mA |  |  |
| Junction temperature range | $\mathrm{T}_{\mathrm{J}}$ | 150 | mA |  |  |
| Storage temperature range | $\mathrm{T}_{\text {STG }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |  |  |

## THERMAL PERFORMANCE

| PARAMETER | SYMBOL | TYP | UNIT |
| :--- | :---: | :---: | :---: |
| Junction-to-ambient thermal resistance | $\mathrm{R}_{\ominus J A}$ | 240 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

TAIWAN
1N4148 / 1N4448 / 1N914B
SEMICONDUCTOR

ELECTRICAL SPECIFICATIONS $\left(T_{A}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| PARAMETER | CONDITIONS |  | SYMBOL | MIN | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Forward voltage per diode ${ }^{(1)}$ | 1N4448,1N914B | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \end{aligned}$ | $V_{F}$ | 0.62 | 0.72 | V |
|  | 1N4148 | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | - | 1.00 |  |
|  | 1N4448,1N914B | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}, \\ & \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \end{aligned}$ |  | - | 1.00 |  |
| Reverse voltage (2) | $\mathrm{I}_{\mathrm{R}}=100 \mu \mathrm{~A}, \mathrm{~T}_{J}=25^{\circ} \mathrm{C}$ |  | $\mathrm{V}_{\mathrm{R}}$ | 100 | - | V |
|  | $\mathrm{I}_{\mathrm{R}}=5 \mu \mathrm{~A}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  |  | 75 | - |  |
| Reverse current (2) | $\mathrm{V}_{\mathrm{R}}=20 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  | $\mathrm{I}_{\mathrm{R}}$ | - | 25 | nA |
|  | $\mathrm{V}_{\mathrm{R}}=75 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |  |  | - | 5 | $\mu \mathrm{A}$ |
| Junction capacitance | $1 \mathrm{MHz}, \mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}$ |  | C | - | 4 | pF |
| Reverse recovery time | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{R}}=6 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=100 \Omega, \\ & \mathrm{I}_{\mathrm{RR}}=1 \mathrm{~mA} \end{aligned}$ |  | $\mathrm{t}_{\mathrm{rr}}$ | - | 4 | ns |

## Notes:

1. Pulse test with $\mathrm{PW}=0.3 \mathrm{~ms}$
2. Pulse test with $P W=30 \mathrm{~ms}$

ORDERING INFORMATION

| PART NO. | PACKAGE | PACKING |
| :---: | :---: | :---: |
| 1N4148 R0G | DO-35 | 10K / 14" Reel |
| 1N4148 R0 | DO-35 | 10K / 14" Reel |
| 1N4148 A0G | DO-35 | 5K / Box(Ammo) |
| 1N4148 A0 | DO-35 | 5K / Box(Ammo) |
| 1N4448 R0G | DO-35 | 10K / 14" Reel |
| 1N4448 R0 | DO-35 | 10K / 14" Reel |
| 1N4448 A0G | DO-35 | 5K / Box(Ammo) |
| 1N4448 A0 | DO-35 | 5K / Box(Ammo) |
| 1N914B R0G | DO-35 | 10K / 14" Reel |
| 1N914B R0 | DO-35 | 10K / 14" Reel |
| 1N914B A0G | DO-35 | 5K / Box(Ammo) |
| 1N914B A0 | DO-35 | 5K / Box(Ammo) |

## CHARACTERISTICS CURVES

( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

Fig. 1 Typical Forward Characteristics


Fig. 3 Admissible Power Dissipation Curve


Fig. 2 Reverse Current VS. Reverse Voltage


Fig. 4 Typical Junction Capacitance


## PACKAGE OUTLINE DIMENSION



| DIM. | Unit (mm) |  | Unit (inch) |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Min | Max | Min | Max |
| A | 0.34 | 0.60 | 0.013 | 0.024 |
| B | 2.90 | 5.08 | 0.114 | 0.200 |
| C | 25.40 | 38.10 | 1.000 | 1.500 |
| D | 1.30 | 2.28 | 0.051 | 0.090 |

## MARKING DIAGRAM



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